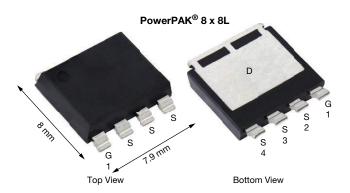
SQJQ186E

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Automotive N-Channel 80 V (D-S) 175 °C MOSFET

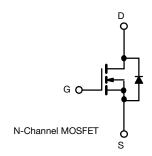


PRODUCT SUMMARY						
V _{DS} (V)	80					
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.0023					
I _D (A)	245					
Configuration	Single					
Package	PowerPAK 8 x 8L					

FEATURES

- TrenchFET[®] Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % Rg and UIS tested
- Thin 1.9 mm height
- Material categorization for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





ABSOLUTE MAXIMUM RATIN	GS (T _C = 25 °C, unless	s otherwise noted	l)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V _{DS}	80	V
Gate-source voltage		V _{GS}	± 20	v
Continuous drain current	T _C = 25 °C	I	245	
Continuous drain current	T _C = 125 °C	ID	141	
Continuous source current (diode conduct	I _S	245	А	
Pulsed drain current ^a		I _{DM}	770	
Single pulse avalanche current	L = 0.1 mH	I _{AS}	58	
Single pulse avalanche energy	L = 0.1 MH	E _{AS}	168	mJ
Maximum power dissipation	T _C = 25 °C	Р	357	W
Maximum power dissipation	T _C = 125 °C	P _D	119	vv
Operating junction and storage temperatu	re range	T _J , T _{stg}	-55 to +175	°C
Soldering recommendations (peak temper		260	C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^b	R _{thJA}	40	°C/W
Junction-to-case (drain)		R _{thJC}	0.42	0/10

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%$

b. When mounted on 1" square PCB (FR4 material)

c. See solder profile (<u>www.vishay.com/doc?73257</u>)

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UNIT

V nA

μΑ

А

Ω

S

рF

nC

Ω

ns

A V ns

nC

ns

А

105

32

31

-3.0

_

-

-

_

210

-

-

_

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SPECIFICATIONS (T_C = 25 °C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	Μ
Static	•			•		
Drain-source breakdown voltage	V _{DS}	V _{GS}	= 0, I _D = 250 μA	80	-	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	2.5	3	:
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, $V_{GS} = \pm 20 V$	-	-	±
		$V_{GS} = 0 V$	V _{DS} = 80 V	-	-	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 80 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	
		$V_{GS} = 0 V$	$V_{DS} = 80 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	5
On-state drain current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	50	-	
		$V_{GS} = 10 V$	I _D = 20 A	-	0.0019	0.0
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}$	$I_D = 20 \text{ A}, \text{T}_\text{J} = 125 \ ^\circ\text{C}$	-	-	0.0
		$V_{GS} = 10 V$	I _D = 20 A, T _J = 175 °C	-	-	0.0
Forward transconductance b	9 _{fs}	V _{DS}	= 15 V, I _D = 15 A	-	90	
Dynamic ^b						
Input capacitance	C _{iss}			-	7537	10
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	1182	1
Reverse transfer capacitance	C _{rss}			-	55	
Total gate charge ^c	Qg			-	123	1
Gate-source charge ^c	Q _{gs}	$V_{GS} = 10 \text{ V}$	$V_{DS} = 40 \text{ V}, I_D = 50 \text{ A}$	-	36	
Gate-drain charge ^c	Q _{gd}			-	26	
Gate resistance	R _g		f = 1 MHz	0.6	1.3	
Turn-on delay time ^c	t _{d(on)}			-	22	
Rise time ^c	t _r	V _{DD}	= 40 V, R _L = 4 Ω,	-	21	
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 10 \text{ A},$	V_{GEN} = 10 V, R_g = 1 Ω	-	53	
Fall time ^c	t _f			-	16	
Source-Drain Diode Ratings and Char	racteristics ^b					
Pulsed current ^a	I _{SM}			-	-	7
Forward voltage	V _{SD}	I _F =	40 A, $V_{GS} = 0 V$	-	0.7	
Body diode reverse recovery time	t _{rr}			-	63	1

Qrr

ta

tb

IRM(REC)

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

Body diode peak reverse recovery current

Body diode reverse recovery charge

Reverse recovery fall time

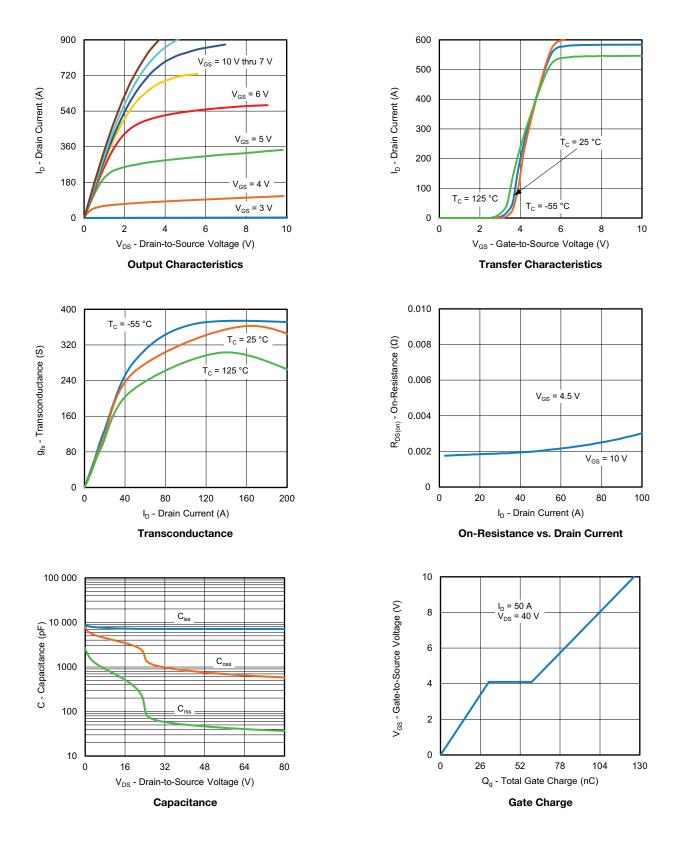
Reverse recovery rise time

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

 $I_F = 10 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



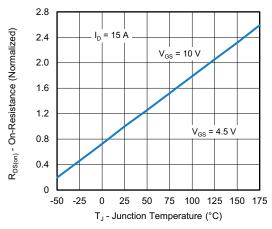
S22-0351-Rev. A, 25-Apr-2022

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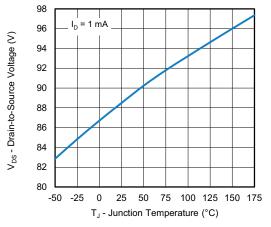
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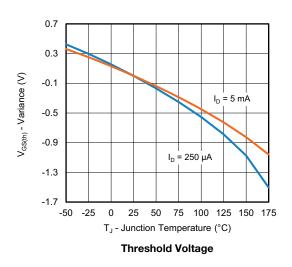
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)

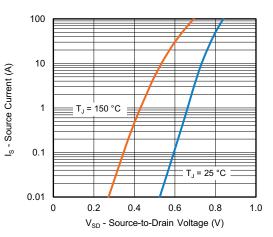


On-Resistance vs. Junction Temperature

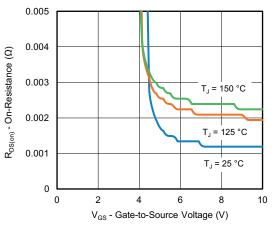


Drain Source Breakdown vs. Junction Temperature

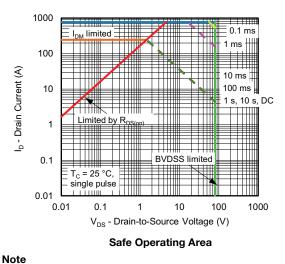




Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



Note a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

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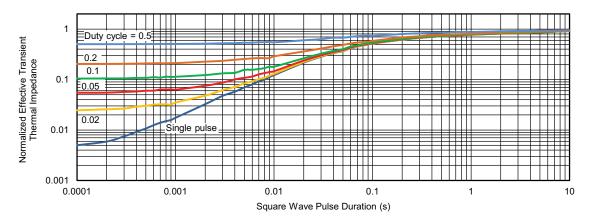
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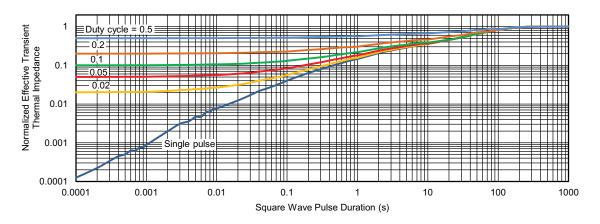
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

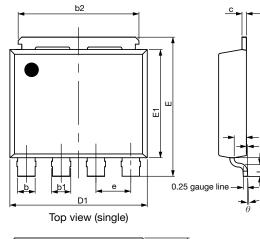


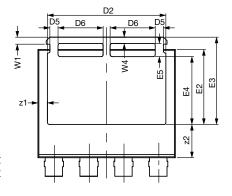
Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg?62006</u>.

PowerPAK[®] 8 x 8L BWL Case Outline 2

A1





Bottom view (single)

1						_ ↑
F	-		-	-	A.	<
l	_					

DIM.		MILLIMETERS			INCHES	
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
А	1.50	1.60	1.70	0.059	0.063	0.067
A1	0.00	-	0.127	0.000	-	0.005
A2	0.655	0.705	0.755	0.026	0.028	0.030
b	0.92	1.00	1.08	0.036	0.039	0.043
b1	1.02	1.10	1.18	0.040	0.043	0.046
b2	6.84	6.94	7.04	0.269	0.273	0.277
С	0.20	0.25	0.30	0.008	0.010	0.012
D1	7.80	7.90	8.00	0.307	0.311	0.315
D2	6.70	6.80	6.90	0.264	0.268	0.272
D5	0.37	0.47	0.57	0.015	0.019	0.022
D6	2.49	2.59	2.69	0.098	0.102	0.106
е	1.97	2.00	2.03	0.078	0.079	0.080
Е	7.90	8.00	8.10	0.311	0.315	0.319
E1	6.12	6.22	6.32	0.241	0.245	0.249
E2	4.21	4.31	4.41	0.166	0.170	0.174
E3	4.92	5.02	5.12	0.194	0.198	0.202
E4	3.80	3.90	4.00	0.150	0.154	0.157
E5	0.65	0.75	0.85	0.026	0.030	0.033
L	0.61	0.68	0.75	0.024	0.027	0.030
L1	1.00	1.07	1.15	0.039	0.042	0.045
W1	0.30	0.40	0.50	0.012	0.016	0.020
W4	0.32	0.37	0.42	0.013	0.015	0.017
z1	0.45	0.55	0.65	0.018	0.022	0.026
z2	1.81	1.91	2.01	0.071	0.075	0.079
θ	0°	-	5°	0°	-	5°
N: S19-0643-F G: 6073	lev. B, 05-Aug-2019					

Note

• Millimeter will govern

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